



HCPL0600, HCPL0601, HCPL0611, HCPL0630, HCPL0631, HCPL0661 High Speed-10 MBit/s Logic Gate Optocouplers

Single Channel: HCPL0600, HCPL0601, HCPL0611

Dual Channel: HCPL0630, HCPL0631, HCPL0661

Features

- Compact SO8 package
- Very high speed-10 MBit/s
- Superior CMR
- Fan-out of 8 over -40°C to +85°C
- Logic gate output
- Strobable output (single channel devices)
- Wired OR-open collector
- U.L. recognized (File # E90700)
- VDE approval pending

- Switching power supplies
- Pulse transformer replacement
- Computer-peripheral interface

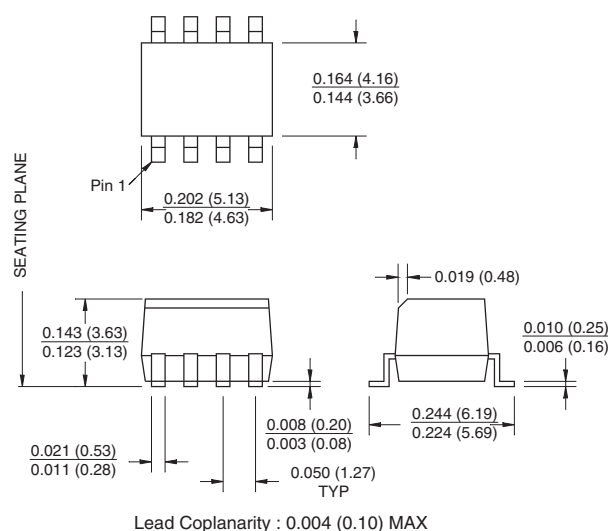
Description

The HCPL06XX optocouplers consist of an AlGaAs LED, optically coupled to a very high speed integrated photo-detector logic gate with a strobable output (single channel devices). The devices are housed in a compact small-outline package. This output features an open collector, thereby permitting wired OR outputs. The HCPL0600, HCPL0601 and HCPL0611 output consists of bipolar transistors on a bipolar process while the HCPL0630, HCPL0631, and HCPL0661 output consists of bipolar transistors on a CMOS process for reduced power consumption. The coupled parameters are guaranteed over the temperature range of -40°C to +85°C. A maximum input signal of 5 mA will provide a minimum output sink current of 13 mA (fan out of 8). An internal noise shield provides superior common mode rejection.

Applications

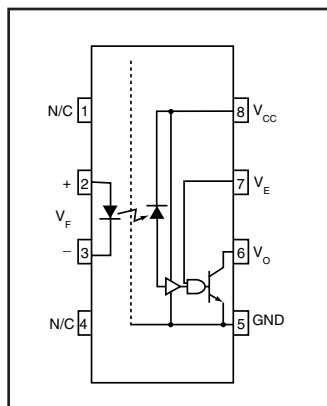
- Ground loop elimination
- LSTTL to TTL, LSTTL or 5-volt CMOS
- Line receiver, data transmission
- Data multiplexing

Package Dimensions

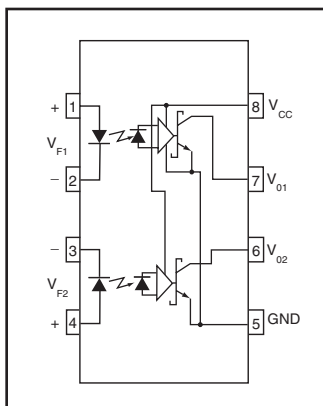


NOTE

All dimensions are in inches (millimeters)



Single-channel circuit
drawing (HCPL0600, HCPL0601
and HCPL0611)



Dual-channel circuit
drawing (HCPL0630, HCPL0631
and HCPL0661)

TRUTH TABLE (Positive Logic)

Input	Enable	Output
H	H	L
L	H	H
H	L	H
L	L	H
H*	NC*	L*
L*	NC*	H*

*Dual channel devices or single channel devices with pin 7 not connected.
A 0.1 μ F bypass capacitor must be connected between pins 8 and 5. (See note 1)

Absolute Maximum Ratings (No derating required up to 85°C)

Symbol	Parameter		Value	Units
T _{STG}	Storage Temperature		-40 to +125	°C
T _{OPR}	Operating Temperature		-40 to +85	°C
EMITTER				
I _F	DC/Average Forward Input Current (each channel)	Single Channel	50	mA
		Dual Channel		
V _E	Enable Input Voltage Not to exceed VCC by more than 500mV	Single Channel	5.5	V
V _R	Reverse Input Voltage (each channel)		5.0	V
P _I	Power Dissipation	Single Channel	45	mW
		Dual Channel		
DETECTOR				
V _{CC} (1 minute max)	Supply Voltage		7.0	V
I _O	Output Current (each channel)		50	mA
V _O	Output Voltage (each channel)		7.0	V
P _O	Collector Output Power Dissipation	Single Channel	85	mW
		Dual Channel		

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
I _{FL}	Input Current, Low Level	0	250	μA
I _{FH}	Input Current, High Level	*6.3	15	mA
V _{CC}	Supply Voltage, Output	4.5	5.5	V
V _{EL}	Enable Voltage, Low Level	0	0.8	V
V _{EH}	Enable Voltage, High Level	2.0	V _{CC}	V
T _A	Operating Temperature	-40	+85	°C
N	Fan Out (TTL load)		8	TTL Loads
R _L	Output Pull-up	330	4K	Ω

*6.3 mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0 mA or less

Electrical Characteristics (T_A = -40°C to +85°C Unless otherwise specified.)

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Min	Typ**	Max	Unit
V _F	EMITTER Input Forward Voltage	(I _F = 10 mA)			1.8	V
		T _A = 25°C			1.75	
B _{VR}	Input Reverse Breakdown Voltage	(I _R = 10 μA)	5.0			V
C _{IN}	Input Capacitance	(V _F = 0, f = 1 MHz)				pF
ΔV _F /ΔT _A	Input Diode Temperature Coefficient	(I _F = 10 mA)				mV/°C
I _{CCH}	DETECTOR High Level Supply Current	(V _E = 0.5 V)	Single Channel		10	mA
		(I _F = 0 mA, V _{CC} = 5.5 V)	Dual Channel		15	
I _{CCL}	Low Level Supply Current	(V _E = 0.5 V)	Single Channel		13	mA
		(I _F = 10 mA, V _{CC} = 5.5 V)	Dual Channel		21	
I _{EL}	Low Level Enable Current	(V _{CC} = 5.5 V, V _E = 0.5 V)	Single Channel		-1.6	mA
I _{EH}	High Level Enable Current	(V _{CC} = 5.5 V, V _E = 2.0 V)	Single Channel		-1.6	mA
V _{EH}	High Level Enable Voltage	(V _{CC} = 5.5 V, I _F = 10 mA)	Single Channel	2.0		V
V _{EL}	Low Level Enable Voltage	(V _{CC} = 5.5 V, I _F = 10 mA)(Note 2)	Single Channel		0.8	V

Switching Characteristics (T_A = -40°C to +85°C, V_{CC} = 5 V, I_F = 7.5 mA Unless otherwise specified.)

Symbol	AC Characteristics		Test Conditions	Device	Min	Typ	Max	Unit
T _{PLH}	Propagation Delay Time to Output High Level		(Note 3) (T _A =25°C) (R _L = 350Ω, C _L = 15 pF) (Fig. 20)	All	20		75	ns
							100	
T _{PHL}	Propagation Delay Time to Output Low Level		(Note 4) (T _A =25°C) (R _L = 350Ω, C _L = 15 pF) (Fig. 20)	All	25		75	ns
							100	
T _{PHL} -T _{PLH}	Pulse Width Distortion		(R _L = 350Ω, C _L = 15 pF) (Fig. 20)	All			35	ns
t _r	Output Rise Time (10-90%)	(R _L = 350Ω, C _L = 15 pF)	(Note 5) (Fig. 20)	All		50		ns
t _f	Output Fall Time (90-10%)	(R _L = 350Ω, C _L = 15 pF)	(Note 6) (Fig. 20)	All		12		ns
t _{ELH}	Enable Propagation Delay Time to Output High Level	(I _F = 7.5 mA, V _{EH} = 3.5 V) (R _L = 350Ω, C _L = 15 pF) (Note 7) (Fig. 21)		HCPL0600 HCPL0601 HCPL0611		20		ns
t _{EHL}	Enable Propagation Delay Time to Output Low Level	(I _F = 7.5 mA, V _{EH} = 3.5 V) (R _L = 350Ω, C _L = 15 pF) (Note 8) (Fig. 21)		HCPL0600 HCPL0601 HCPL0611		20		ns
ICM _H	Common Mode Transient Immunity (at Output High Level)	(R _L = 350Ω) (T _A =25°C) (I _F = 0 mA, V _{OH} (Min.) = 2.0 V)(Note 9)(Fig. 22, 23)	IV _{CM} = 10 V	HCPL0600 HCPL0630				V/μs
			IV _{CM} = 50 V	HCPL0601 HCPL0631	5000			
			IV _{CM} = 1,000 V	HCPL0611	10,000			
				HCPL0661	25,000			
ICM _L	Common Mode Transient Immunity (at Output Low Level)	(R _L = 350Ω) (T _A =25°C) (I _F = 7.5 mA, V _{OL} (Max.) = 0.8 V)(Note 10)(Fig. 22, 23)	IV _{CM} = 10 V	HCPL0600 HCPL0630				V/μs
			IV _{CM} = 50 V	HCPL0601 HCPL0631	5000			
			IV _{CM} = 1,000 V	HCPL0611	10,000			
				HCPL0661	25,000			

Transfer Characteristics ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ Unless otherwise specified.)

Symbol	DC Characteristics	Test Conditions	Min	Typ**	Max	Unit
I_{OH}	High Level Output Current	($V_{CC} = 5.5\text{ V}$, $V_O = 5.5\text{ V}$) ($I_F = 250\text{ }\mu\text{A}$, $V_E = 2.0\text{ V}$) (Note 2)			100	μA
V_{OL}	Low Level Output Voltage	($V_{CC} = 5.5\text{ V}$, $I_F = 5\text{ mA}$) ($V_E = 2.0\text{ V}$, $I_{OL} = 13\text{ mA}$) (Note 2)			0.6	V
I_{FT}	Input Threshold Current	($V_{CC} = 5.5\text{ V}$, $V_O = 0.6\text{ V}$, $V_E = 2.0\text{ V}$, $I_{OL} = 13\text{ mA}$)			5	mA

Isolation Characteristics ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ Unless otherwise specified.)

Symbol	Characteristics	Test Conditions	Min	Typ**	Max	Unit
I_{I-O}	Input-Output Insulation Leakage Current	(Relative humidity = 45%) ($T_A = 25^\circ\text{C}$, $t = 5\text{ s}$) ($V_{I-O} = 3000\text{ VDC}$) (Note 11)			1.0*	μA
V_{ISO}	Withstand Insulation Test Voltage	($R_H < 50\%$, $T_A = 25^\circ\text{C}$) ($I_{I-O} \leq 2\text{ }\mu\text{A}$, $t = 1\text{ min.}$) (Note 11)	3750			V_{RMS}
R_{I-O}	Resistance (Input to Output)	($V_{I-O} = 500\text{ V}$) (Note 11)		10^{12}		Ω
C_{I-O}	Capacitance (Input to Output)	($f = 1\text{ MHz}$) (Note 11)		0.6		pF

** All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

NOTES

1. The V_{CC} supply to each optoisolator must be bypassed by a $0.1\text{ }\mu\text{F}$ capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins of each device.
2. Enable Input - No pull up resistor required as the device has an internal pull up resistor.
3. t_{PLH} - Propagation delay is measured from the 3.75 mA level on the HIGH to LOW transition of the input current pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
4. t_{PHL} - Propagation delay is measured from the 3.75 mA level on the LOW to HIGH transition of the input current pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
5. t_r - Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
6. t_f - Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
7. t_{ELH} - Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
8. t_{EHL} - Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
9. CM_H - The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the high state (i.e., $V_{OUT} > 2.0\text{ V}$). Measured in volts per microsecond (V/ μs).
10. CM_L - The maximum tolerable rate of fall of the common mode voltage to ensure the output will remain in the low output state (i.e., $V_{OUT} < 0.8\text{ V}$). Measured in volts per microsecond (V/ μs).
11. Device considered a two-terminal device: Pins 1,2,3 and 4 shorted together, and Pins 5,6,7 and 8 shorted together.

Typical Performance Curves (HCPL0600, HCPL0601 and HCPL0611 only)

Fig. 1 Forward Current vs. Input Forward Voltage

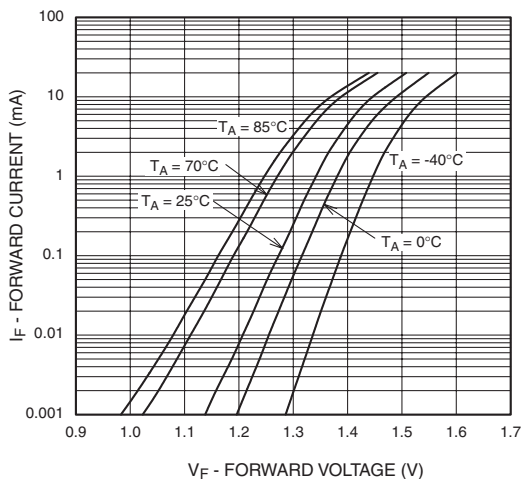


Fig. 2 Output Voltage vs. Forward Current

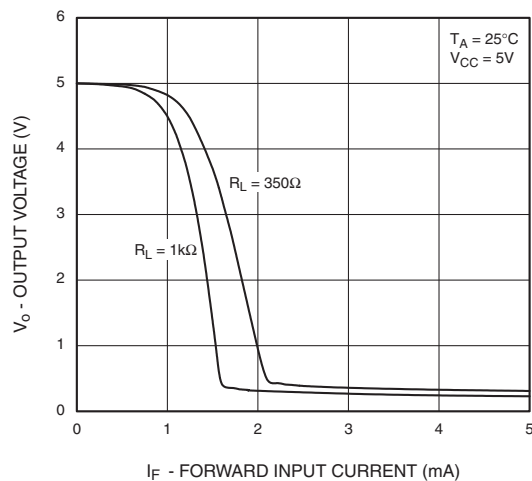


Fig. 3 Input Threshold Current vs. Temperature

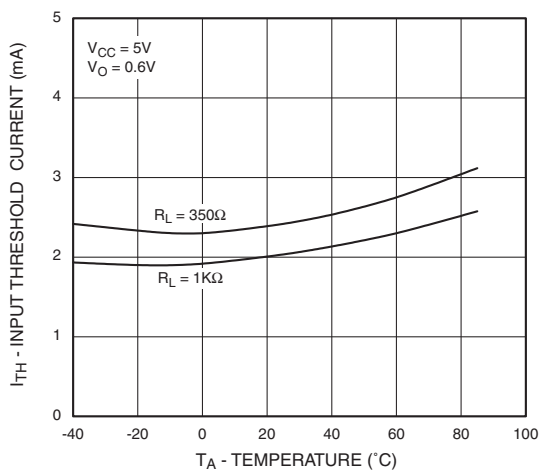
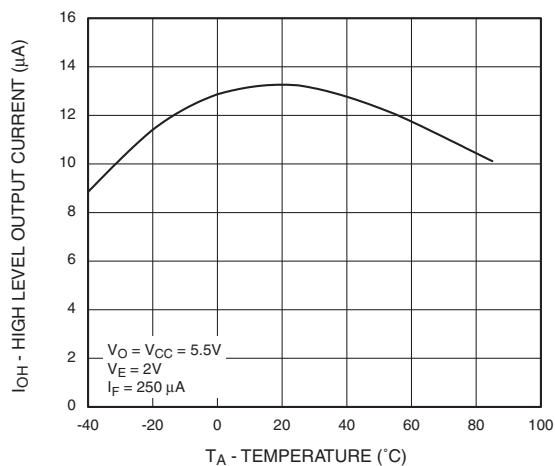


Fig. 4 High Level Output Current vs. Temperature



Typical Performance Curves (HCPL0600, and HCPL0601 and HCPL0611 only)

Fig. 5 Low Level Output Voltage vs. Temperature

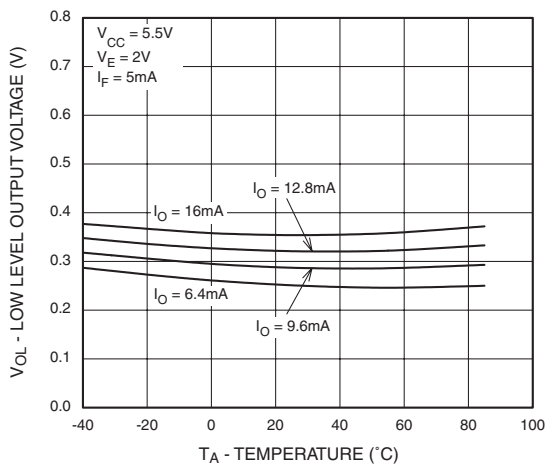


Fig. 6 Low Level Output Current vs. Temperature

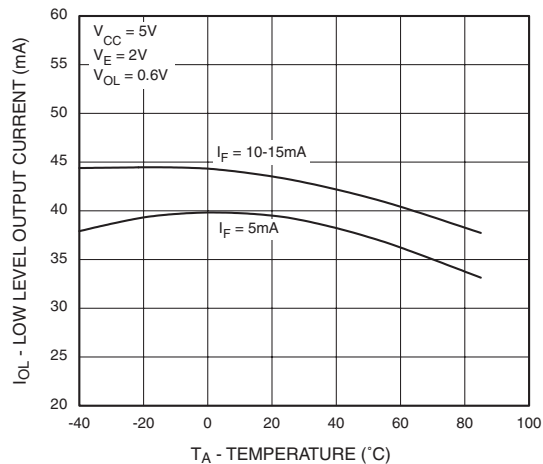


Fig. 7 Propagation Delay vs. Temperature

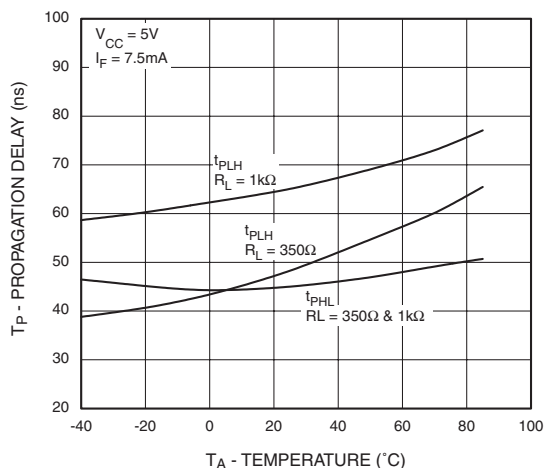
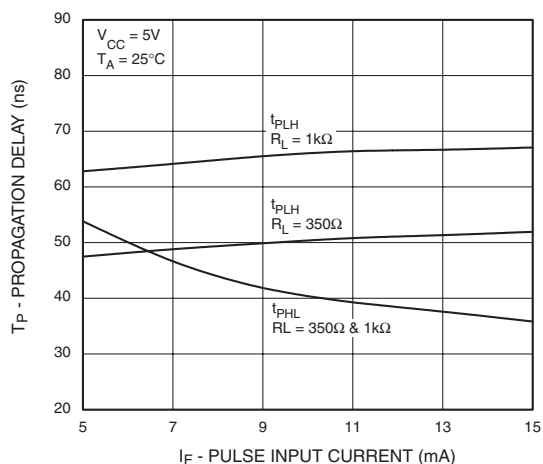


Fig. 8 Propagation Delay vs. Pulse Input Current



Typical Performance Curves (HCPL0600, HCPL0601 and HCPL0611 only)

Fig. 9 Typical Enable Propagation Delay vs. Temperature

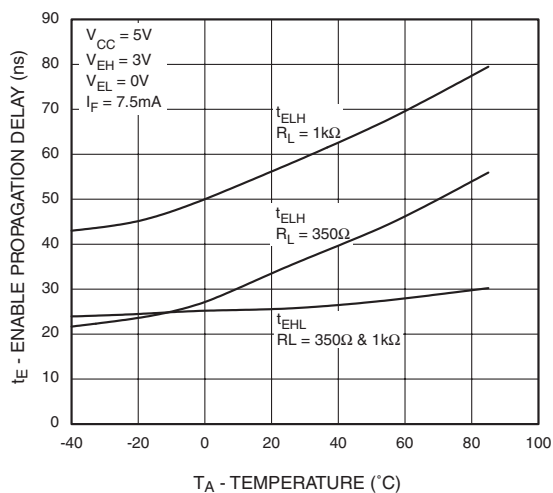


Fig. 10 Typical Rise and Fall Time vs. Temperature

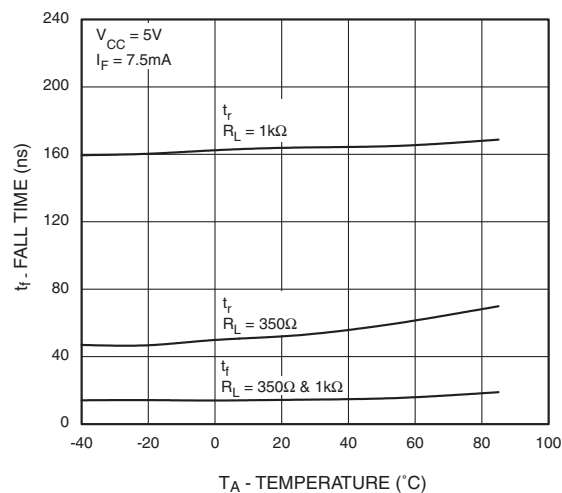
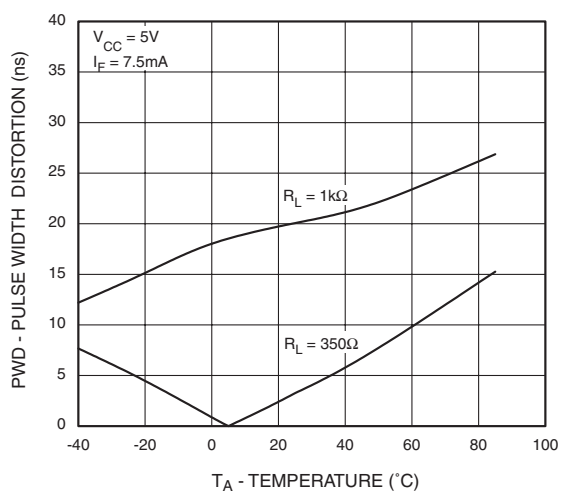


Fig. 11 Typical Pulse Width Distortion vs. Temperature



Typical Performance Curves (HCPL0630, HCPL0631 and HCPL0661 only)

Fig. 12 Input Forward Current vs. Forward Voltage

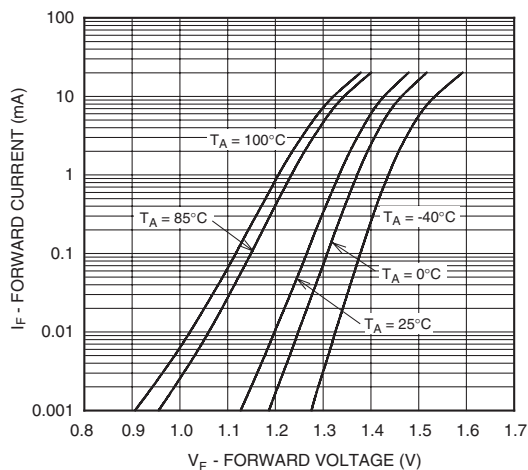


Fig. 13 Input Threshold Current vs. Ambient Temperature

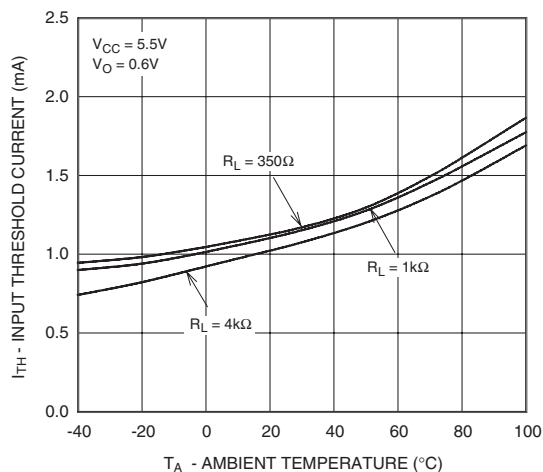


Fig. 14 High Level Output Current vs. Ambient Temperature

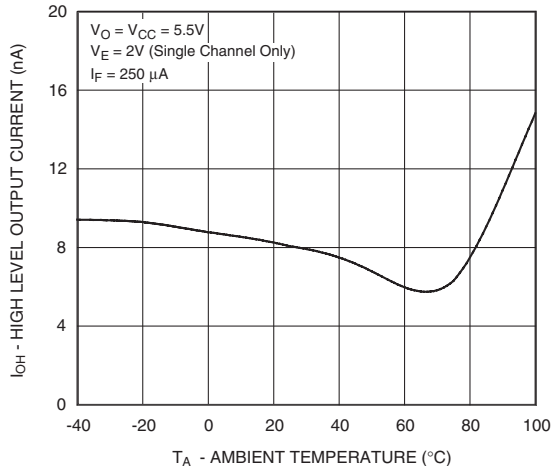


Fig. 15 Low Level Output Current vs. Ambient Temperature

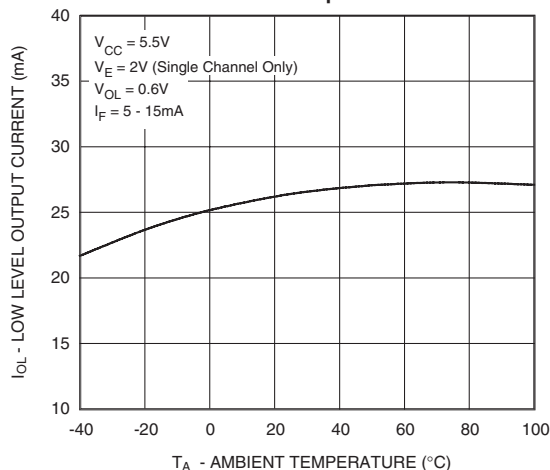


Fig. 16 Low Level Output Voltage vs. Ambient Temperature

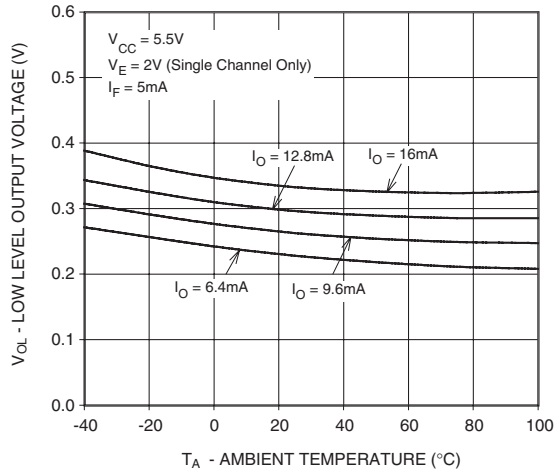
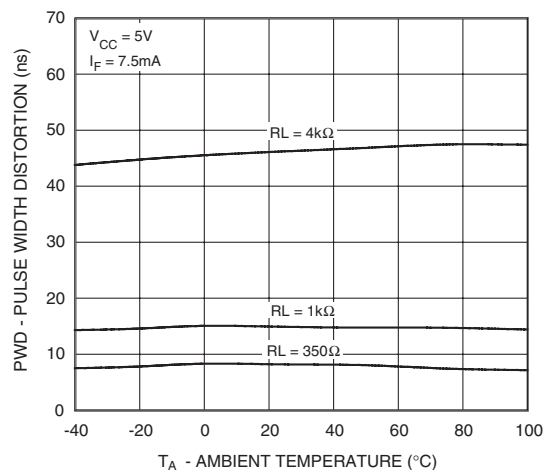


Fig. 17 Pulse Width Distortion vs. Ambient Temperature



Typical Performance Curves (HCPL0630, HCPL0631 and HCPL0661 only)

Fig. 18 Propagation Delay vs. Ambient Temperature

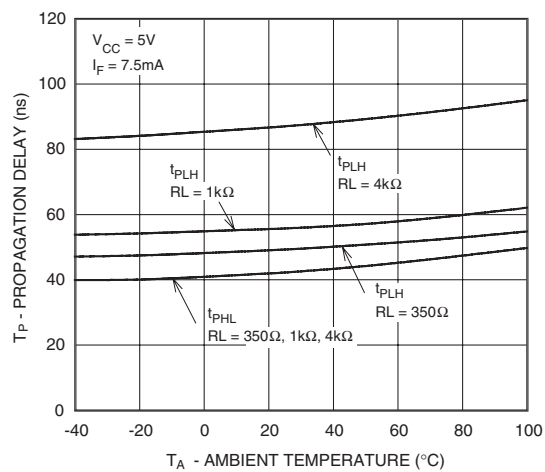
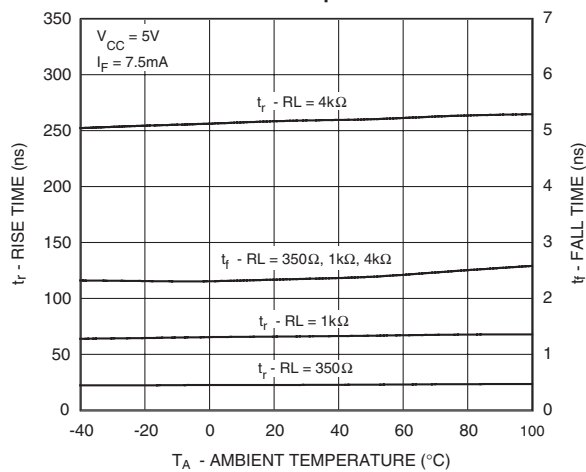
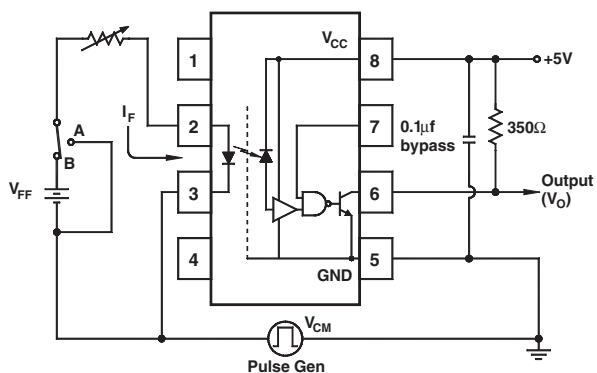


Fig. 19 Rise and Fall Times vs. Ambient Temperature



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Test Circuit for HCPL0600, HCPL0601, and HCPL0611

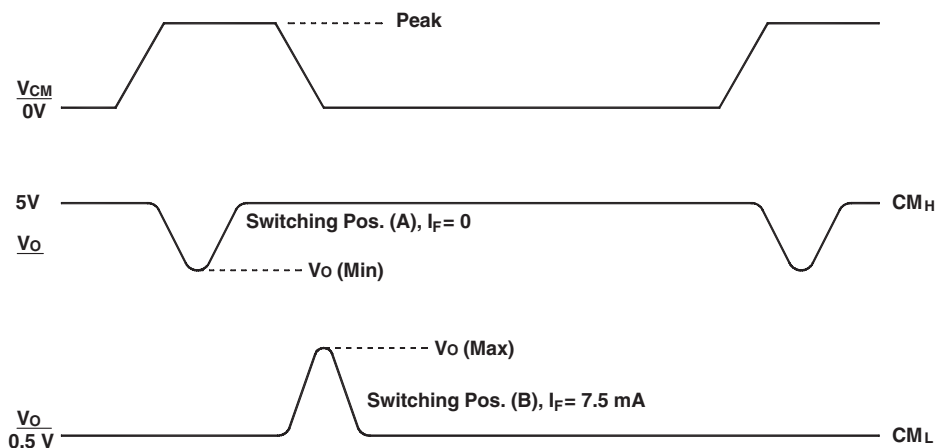
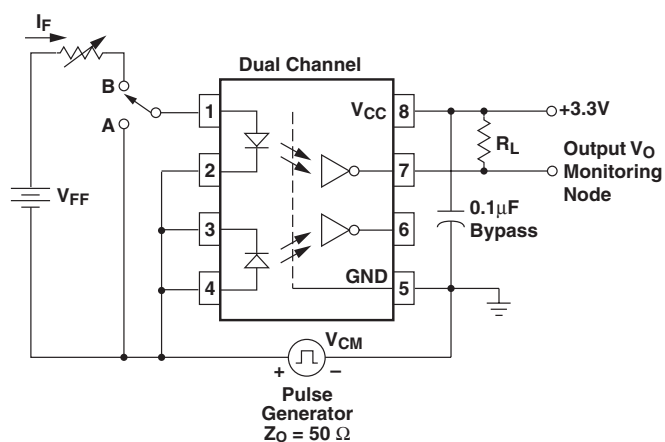


Fig. 22 Test Circuit Common Mode Transient Immunity
(HCPL0600, HCPL0601 and HCPL0611)



Test Circuit for HCPL0630, HCPL0631 and HCPL0661

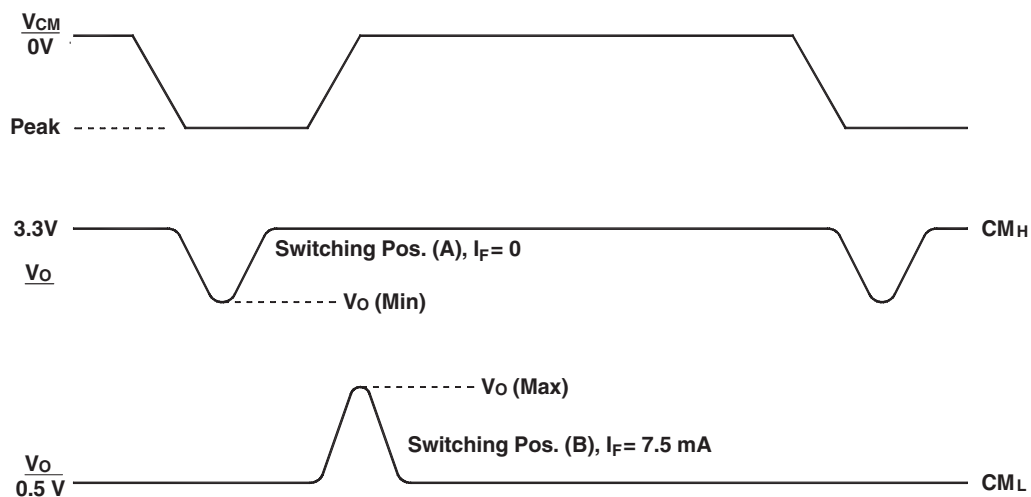
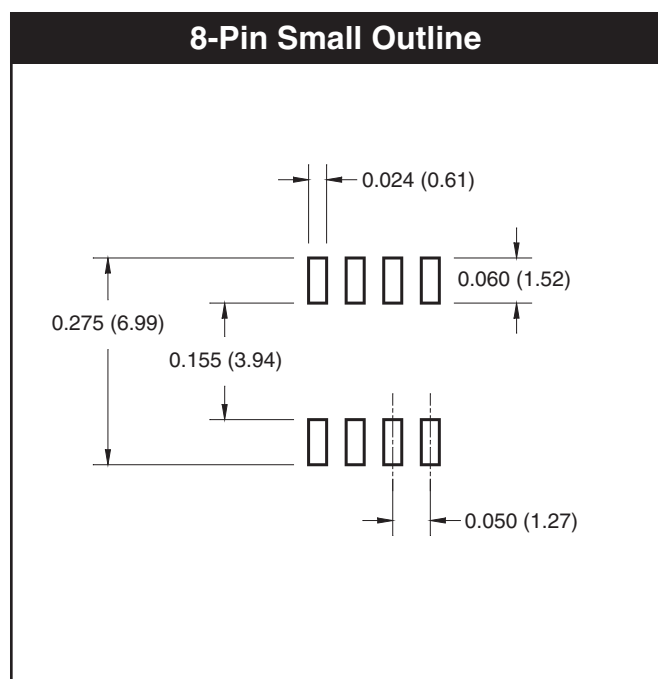


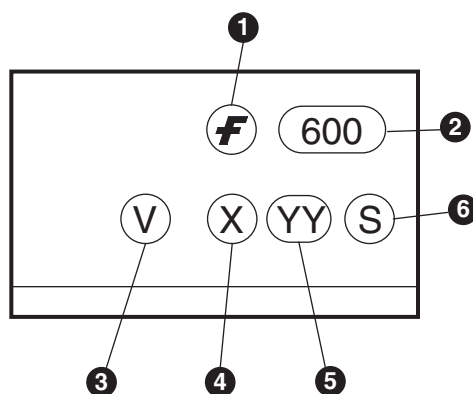
Fig. 23 Test Circuit Common Mode Transient Immunity
(HCPL0630, HCPL0631 and HCPL0661)



Ordering Information

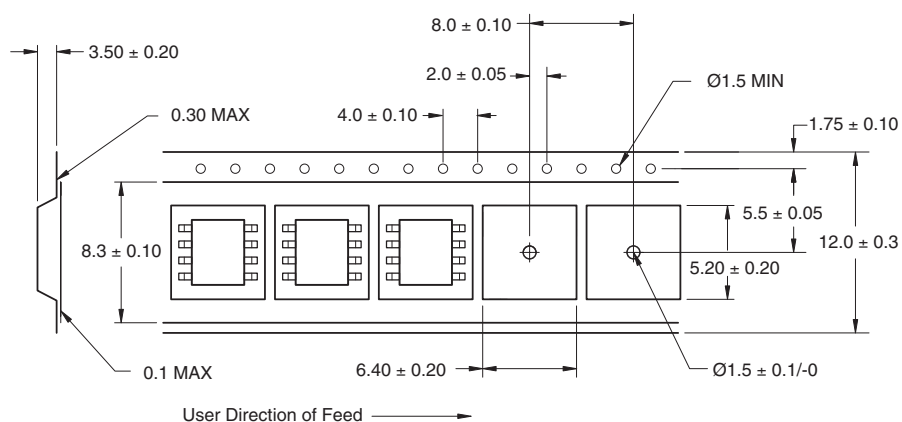
Option	Order Entry Identifier	Description
No Suffix	HCPL0600	Shipped in tubes (50 units per tube)
V	HCPL0600V	VDE0884 (pending approval)
R1	HCPL0600R1	Tape and Reel (500 units per reel)
R1V	HCPL0600R1V	VDE0884 (pending approval), Tape and Reel (500 units per reel)
R2	HCPL0600R2	Tape and Reel (2500 units per reel)
R2V	HCPL0600R2V	VDE0884 (pending approval), Tape and Reel (2500 units per reel)

Marking Information

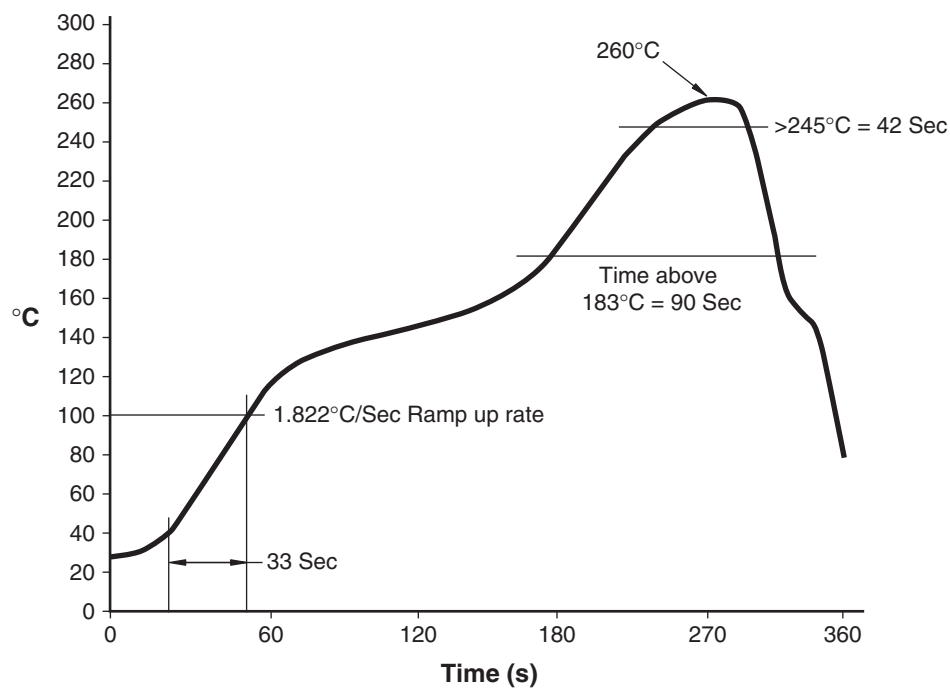


Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., '3'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

Carrier Tape Specifications



Reflow Profile



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Bottomless™	FPS™	MICROCOUPLER™	PowerTrench®	SuperSOT™-6
Build it Now™	FRFET™	MicroFET™	QFET®	SuperSOT™-8
CoolFET™	GlobalOptoisolator™	MicroPak™	QS™	SyncFET™
CROSSVOLT™	GTO™	MICROWIRE™	QT Optoelectronics™	TCM™
DOME™	HiSeC™	MSX™	Quiet Series™	TinyLogic®
EcoSPARK™	I ² C™	MSXPro™	RapidConfigure™	TINYOPTO™
E ² CMOS™	i-Lo™	OCX™	RapidConnect™	TruTranslation™
EnSigna™	ImpliedDisconnect™	OCXPro™	μSerDes™	UHC™
FACT™	IntelliMAX™	OPTOLOGIC®	ScalarPump™	UniFET™
FACT Quiet Series™		OPTOPLANAR™	SILENT SWITCHER®	UltraFET®
Across the board. Around the world.™		PACMAN™	SMART START™	VCX™
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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. I19



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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.